

SNx4HC377 具有时钟使能端的八路 D 类触发器

1 特性

- 2V 至 6V 的宽工作电压范围
- 输出可驱动多达 10 个 LSTTL 负载
- 低功耗， I_{CC} 最大值为 80 μ A
- t_{pd} 典型值 = 12 ns
- ± 4 mA 输出驱动 (在 5V 时)
- 低输出电流，最大值 1 μ A
- 八个具有单轨输出的触发器
- 时钟启用已锁存，以避免时钟故障

2 应用

- 缓冲/存储寄存器
- 移位寄存器
- 图形发生器

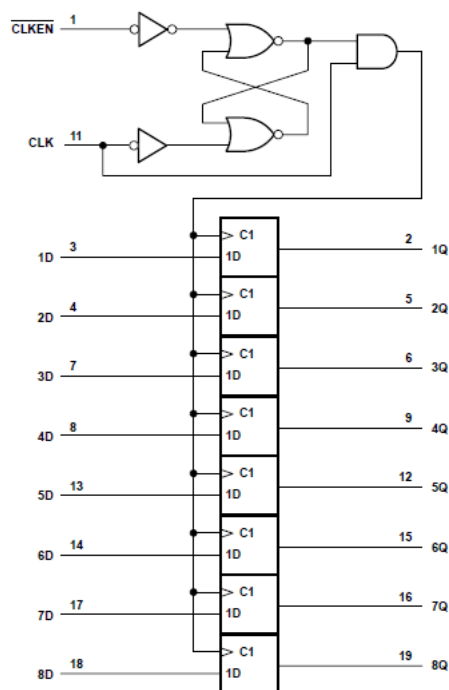
3 说明

这些器件为具有使能输入的正缘触发八路 D 型触发器。'HC377 器件与 'HC273 器件类似，但具有锁存的时钟使能 (CLKEN) 输入，而不是常见的清零。

器件信息

器件型号	封装 ⁽¹⁾	封装尺寸 (标称值)
SN74HC377DW	SOIC (20)	12.80mm × 7.50mm
SN74HC377N	PDIP (20)	25.40mm × 6.35mm
SN74HC377NS	SO (20)	15.00 mm × 5.30 mm
SN54HC377J	CDIP (20)	26.92mm × 6.92mm
SNJ54HC377FK	LCCC (20)	8.89mm × 8.45mm

(1) 如需了解所有可用封装，请参阅数据表末尾的可订购产品附录。



功能方框图



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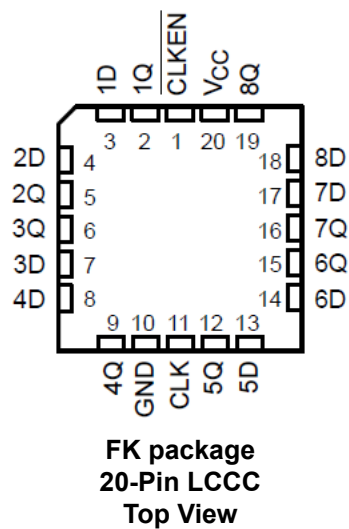
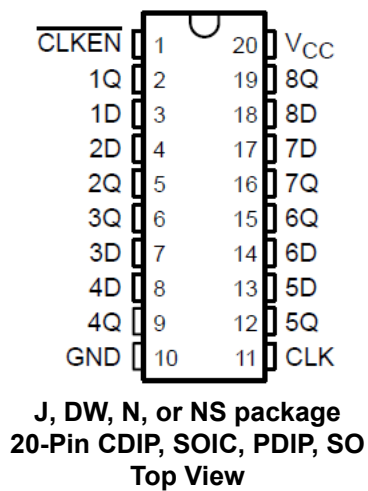
4 Revision History

注：以前版本的页码可能与当前版本的页码不同

Changes from Revision C (January 2022) to Revision D (May 2022)	Page
Junction-to-ambient thermal resistance values increased. DW was 58 is now 109.1, N was 69 is now 84.6, NS was 60 is now 113.4.....	4

Changes from Revision B (January 2003) to Revision C (January 2022)	Page
更新了整个文档中的编号、格式、表格、图和交叉参考，以反映现代数据表标准.....	1

5 Pin Configuration and Functions



6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
V_{CC}	Supply voltage range	-0.5	7	V
I_{IK}	Input clamp current ⁽²⁾	$(V_I < 0 \text{ or } V_I > V_{CC})$		± 20 mA
I_{OK}	Output clamp current ⁽²⁾	$(V_O < 0 \text{ or } V_O > V_{CC})$		± 20 mA
I_O	Continuous output current	$(V_O = 0 \text{ to } V_{CC})$		± 25 mA
	Continuous current through V_{CC} or GND			± 50 mA
T_J	Junction temperature			150 °C
T_{stg}	Storage temperature			-65 150 °C

- (1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

6.2 Recommended Operating Conditions⁽¹⁾

			SN54HC377			SN74HC377			UNIT
			MIN	NOM	MAX	MIN	NOM	MAX	
V_{CC}	Supply voltage		2	5	6	2	5	6	V
V_{IH}	High-level input voltage	$V_{CC} = 2 \text{ V}$	1.5			1.5			V
		$V_{CC} = 4.5 \text{ V}$	3.15			3.15			
		$V_{CC} = 6 \text{ V}$	4.2			4.2			
V_{IL}	Low-level input voltage	$V_{CC} = 2 \text{ V}$			0.5			0.5	V
		$V_{CC} = 4.5 \text{ V}$			1.35			1.35	
		$V_{CC} = 6 \text{ V}$			1.8			1.8	
V_I	Input voltage		0		V_{CC}	0		V_{CC}	V
V_O	Output voltage		0		V_{CC}	0		V_{CC}	V
t_t	Input transition rise/fall time	$V_{CC} = 2 \text{ V}$			1000			1000	ns
		$V_{CC} = 4.5 \text{ V}$			500			500	
		$V_{CC} = 6 \text{ V}$			400			400	
T_A	Operating free-air temperature		- 55		125	- 40		85	°C

- (1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report Implications of Slow or Floating SMOS Inputs, literature number [SCBA004](#).

6.3 Thermal Information

THERMAL METRIC		DW (SOIC)	N (PDIP)	NS (SO)	UNIT
		20 PINS	20 PINS	20 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance ⁽¹⁾	109.1	84.6	113.4	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	76	72.5	78.6	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	77.6	65.3	78.4	°C/W
ψ_{JT}	Junction-to-top characterization parameter	51.5	55.3	47.1	°C/W
ψ_{JB}	Junction-to-top characterization parameter	77.1	65.2	78.1	°C/W

6.3 Thermal Information (continued)

THERMAL METRIC		DW (SOIC)	N (PDIP)	NS (SO)	UNIT
		20 PINS	20 PINS	20 PINS	
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	N/A	N/A	N/A	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC package thermal metrics](#) application report.

6.4 Electrical Characteristics

PARAMETER	TEST CONDITIONS ⁽¹⁾	V_{CC} (V)	$T_A = 25^\circ\text{C}$			SN74HC377		SN74HC377		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
V_{OH}	$I_{OH} = -20\ \mu\text{A}$	2	1.9	1.998		1.9		1.9		V
		4.5	4.4	4.499		4.4		4.4		
		6	5.9	5.999		5.9		5.9		
	$I_{OH} = -4\ \text{mA}$	4.5	3.98	4.3		3.7		3.84		
		6	5.48	5.8		5.2		5.34		
V_{OL}	$I_{OL} = 20\ \mu\text{A}$	2		0.002	0.1		0.1		0.1	V
		4.5		0.001	0.1		0.1		0.1	
		6		0.001	0.1		0.1		0.1	
	$I_{OL} = 4\ \text{mA}$	4.5		0.17	0.26		0.4		0.33	
		6		0.15	0.26		0.4		0.33	
I_I	$V_I = V_{CC}$ or 0	6		± 0.1	± 100		± 1000		± 1000	nA
I_{CC}	$V_I = V_{CC}$ or 0. $I_O = 0$	6			8		160		80	μA
C_i		2 to 6		3	10		10		10	pF

- (1) $V_I = V_{IH}$ or V_{IL} , unless otherwise noted.

6.5 Timing Requirements

		V_{CC}	$T_A = 25^\circ\text{C}$		SN54HC377		SN74HC377		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	
f_{clock}	Clock frequency	2		5		3		4	MHz
		4.5		25		16		20	
		6		29		19		23	
t_W	Pulse duration, CLK high or low	2	100		150		125		ns
		4.5	20		30		25		
		6	17		25		21		
t_{su}	Setup time, data before CLK $\uparrow$	D	2	100		150		125	ns
			4.5	20		30		25	
			6	17		25		21	
	CLKEN high or low		2	100		150		125	
			4.5	20		30		25	
			6	17		25		21	
t_h	Hold time, data after LE $\uparrow$	CLKEN inactive or active, data	2	5		5		5	ns
			4.5	5		5		5	
			6	5		5		5	

6.6 Switching Characteristics

over recommended operating free-air temperature range, $C_L = 50$ pF (unless otherwise noted) See [Parameter Measurement Information](#)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CC} (V)	$T_A = 25^\circ\text{C}$			SN54HC377		SN74HC377		UNIT
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
$f_{\max}$			2	5	11		3		4		MHz
			4.5	25	54		16		20		
			6	29	64		19		23		
t_{pd}	CLK	Any	2		56	160		240		200	ns
			4.5		15	32		48		40	
			6		12	27		41		34	
t_t		Any	2		38	75		110		95	ns
			4.5		8	15		22		19	
			6		6	13		19		16	

6.7 Operating Characteristics

$T_A = 25^\circ\text{C}$

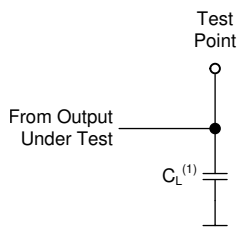
		Test Conditions	TYP	UNIT
C_{pd}	Power dissipation capacitance per flip-flop	No load	30	pF

7 Parameter Measurement Information

Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: $PRR \leq 1 \text{ MHz}$, $Z_O = 50 \Omega$, $t_f < 2.5 \text{ ns}$.

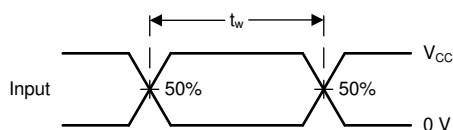
For clock inputs, f_{max} is measured when the input duty cycle is 50%.

The outputs are measured one at a time with one input transition per measurement.

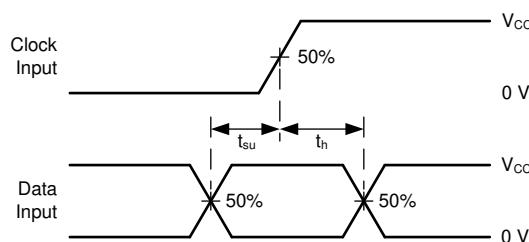


(1) C_L includes probe and test-fixture capacitance.

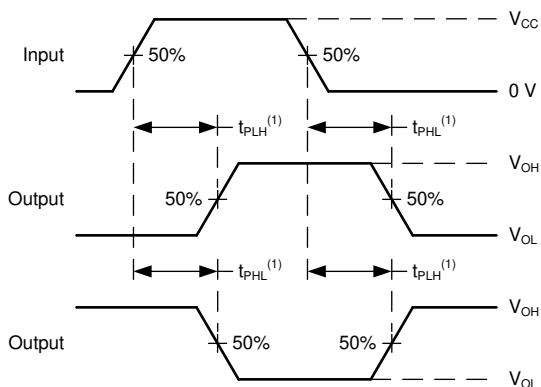
图 7-1. Load Circuit for Push-Pull Outputs



**图 7-2. Voltage Waveforms, Standard CMOS Inputs
Pulse Duration**

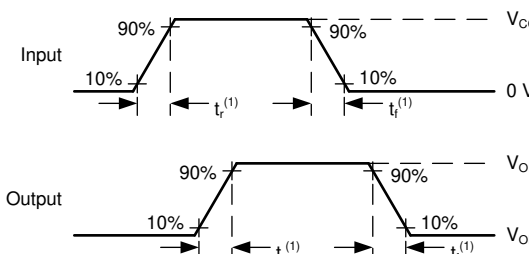


**图 7-3. Voltage Waveforms, Standard CMOS Inputs
Setup and Hold Times**



(1) The greater between t_{PLH} and t_{PHL} is the same as t_{pd} .

**图 7-4. Voltage Waveforms, Propagation Delays for
Standard CMOS Inputs**



(1) The greater between t_r and t_f is the same as t_t .

**图 7-5. Voltage Waveforms, Input and Output
Transition Times for Standard CMOS Inputs**

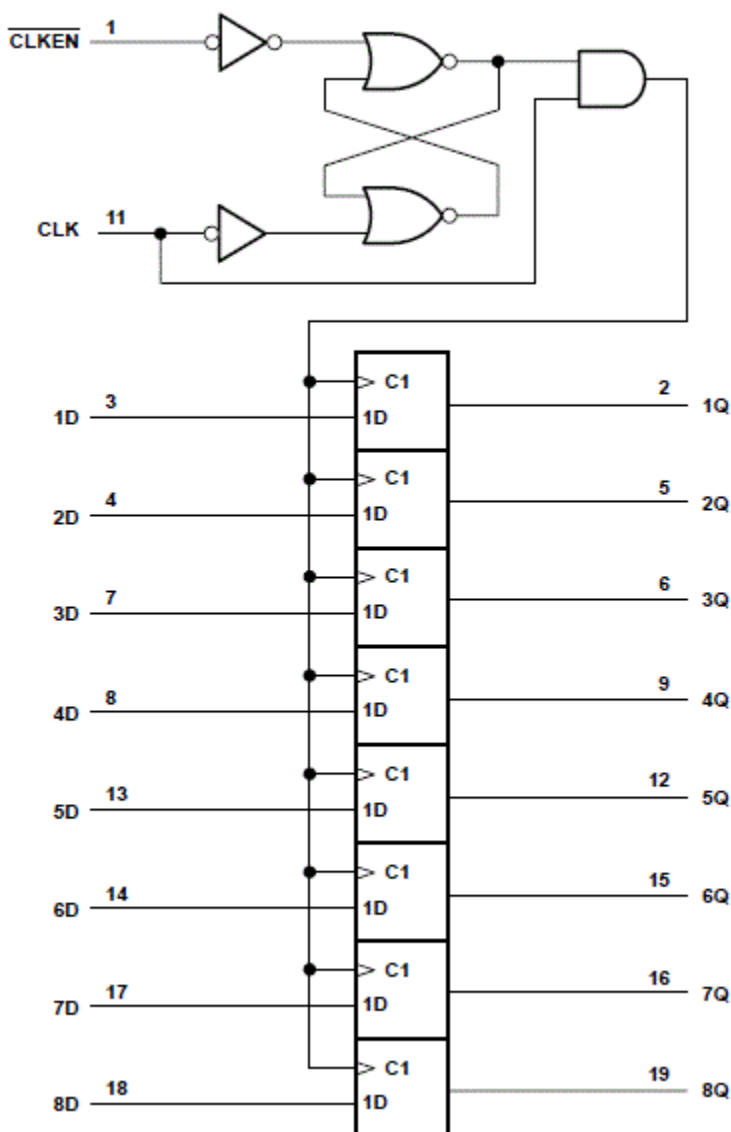
8 Detailed Description

8.1 Overview

These devices are positive-edge-triggered octal D-type flip-flops with an enable input. The ' HC377 devices are similar to the ' HC273 devices, but feature a latched clock-enable ($\overline{\text{CLKEN}}$) input instead of a common clear.

Information at the data (D) inputs meeting the setup time requirements is transferred to the Q outputs on the positive-going edge of the clock (CLK) pulse, if $\overline{\text{CLKEN}}$ is low. Clock triggering occurs at a particular voltage level and is not directly related to the transition time of the positive-going pulse. When CLK is at either the high or low level, the D input has no effect at the output. These devices are designed to prevent false clocking by transitions at $\overline{\text{CLKEN}}$.

8.2 Functional Block Diagram



8.3 Device Functional Modes

**Function Table
(Each Flip-Flop)**

INPUTS			OUTPUT Q
CLKEN	CLK	D	
H	X	X	Q ₀
L	↑	H	H
L	↑	L	L
X	L	X	Q ₀

9 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. A 0.1- μ F capacitor is recommended for this device. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. The 0.1- μ F and 1- μ F capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

10 Layout

10.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices inputs must not ever be left floating. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or V_{CC} , whichever makes more sense for the logic function or is more convenient.

11 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

11.1 Documentation Support

11.1.1 Related Documentation

11.2 接收文档更新通知

要接收文档更新通知，请导航至 ti.com 上的器件产品文件夹。点击 [订阅更新](#) 进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

11.3 支持资源

[TI E2E™ 支持论坛](#) 是工程师的重要参考资料，可直接从专家获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题可获得所需的快速设计帮助。

链接的内容由各个贡献者“按原样”提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的《[使用条款](#)》。

11.4 Trademarks

TI E2E™ is a trademark of Texas Instruments.

所有商标均为其各自所有者的财产。

11.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

11.6 术语表

[TI 术语表](#) 本术语表列出并解释了术语、首字母缩略词和定义。

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
5962-87807012A	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962- 87807012A SNJ54HC 377FK
5962-8780701RA	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8780701RA SNJ54HC377J
SN54HC377J	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	SN54HC377J
SN54HC377J.A	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	SN54HC377J
SN74HC377DW	Obsolete	Production	SOIC (DW) 20	-	-	Call TI	Call TI	-40 to 85	HC377
SN74HC377DWR	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC377
SN74HC377DWR.A	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC377
SN74HC377N	Active	Production	PDIP (N) 20	20 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	SN74HC377N
SN74HC377N.A	Active	Production	PDIP (N) 20	20 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	SN74HC377N
SN74HC377N.B	Active	Production	PDIP (N) 20	20 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	SN74HC377N
SN74HC377NE4	Active	Production	PDIP (N) 20	20 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	SN74HC377N
SN74HC377NSR	Active	Production	SOP (NS) 20	2000 LARGE T&R	Yes	NIPDAU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC377
SN74HC377NSR.A	Active	Production	SOP (NS) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC377
SNJ54HC377FK	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962- 87807012A SNJ54HC 377FK
SNJ54HC377FK.A	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962- 87807012A SNJ54HC 377FK
SNJ54HC377J	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8780701RA SNJ54HC377J
SNJ54HC377J.A	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8780701RA SNJ54HC377J

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

(2) Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) RoHS values: Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN54HC377, SN74HC377 :

- Catalog : [SN74HC377](#)
- Military : [SN54HC377](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product
- Military - QML certified for Military and Defense Applications

TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74HC377DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74HC377NSR	SOP	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74HC377DWR	SOIC	DW	20	2000	356.0	356.0	45.0
SN74HC377NSR	SOP	NS	20	2000	356.0	356.0	45.0

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
5962-87807012A	FK	LCCC	20	55	506.98	12.06	2030	NA
SN74HC377N	N	PDIP	20	20	506	13.97	11230	4.32
SN74HC377N.A	N	PDIP	20	20	506	13.97	11230	4.32
SN74HC377N.B	N	PDIP	20	20	506	13.97	11230	4.32
SN74HC377NE4	N	PDIP	20	20	506	13.97	11230	4.32
SNJ54HC377FK	FK	LCCC	20	55	506.98	12.06	2030	NA
SNJ54HC377FK.A	FK	LCCC	20	55	506.98	12.06	2030	NA

MECHANICAL DATA

NS (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

14-PINS SHOWN



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.

J (R-GDIP-T**)

14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



PINS ** DIM	14	16	18	20
A	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC
B MAX	0.785 (19,94)	.840 (21,34)	0.960 (24,38)	1.060 (26,92)
B MIN	—	—	—	—
C MAX	0.300 (7,62)	0.300 (7,62)	0.310 (7,87)	0.300 (7,62)
C MIN	0.245 (6,22)	0.245 (6,22)	0.220 (5,59)	0.245 (6,22)



4040083/F 03/03

- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. This package is hermetically sealed with a ceramic lid using glass frit.
 - D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
 - E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

GENERIC PACKAGE VIEW

FK 20

LCCC - 2.03 mm max height

8.89 x 8.89, 1.27 mm pitch

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



4229370VA\

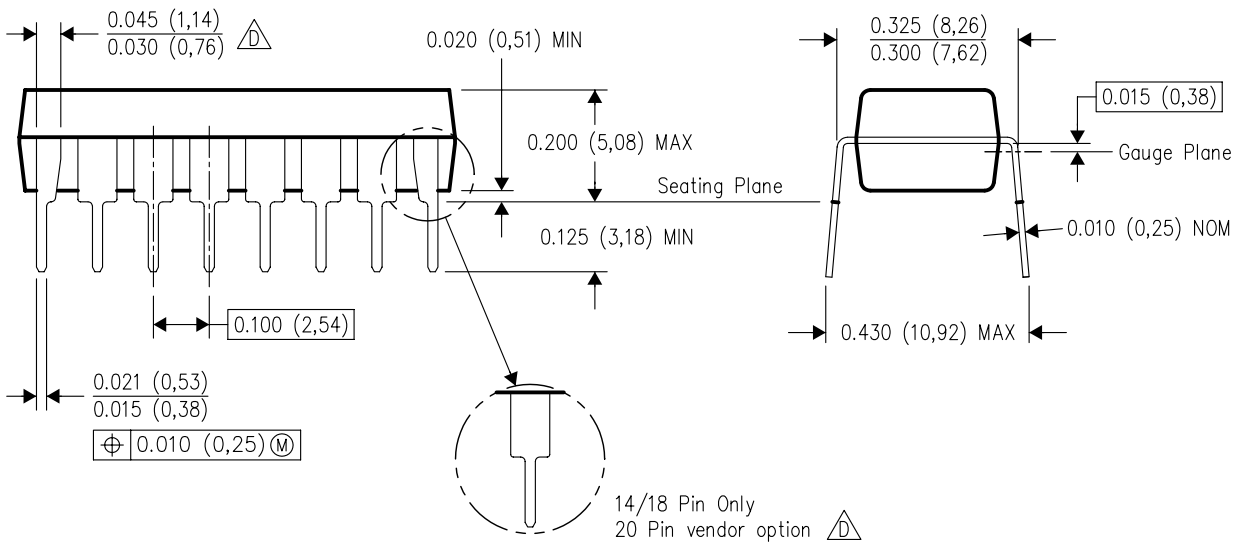
N (R-PDIP-T**)

16 PINS SHOWN

PLASTIC DUAL-IN-LINE PACKAGE



PINS **	14	16	18	20
DIM				
A MAX	0.775 (19,69)	0.775 (19,69)	0.920 (23,37)	1.060 (26,92)
A MIN	0.745 (18,92)	0.745 (18,92)	0.850 (21,59)	0.940 (23,88)
MS-001 VARIATION	AA	BB	AC	AD



4040049/E 12/2002

- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
 - The 20 pin end lead shoulder width is a vendor option, either half or full width.



NOTES:

1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
5. Reference JEDEC registration MS-013.

EXAMPLE BOARD LAYOUT

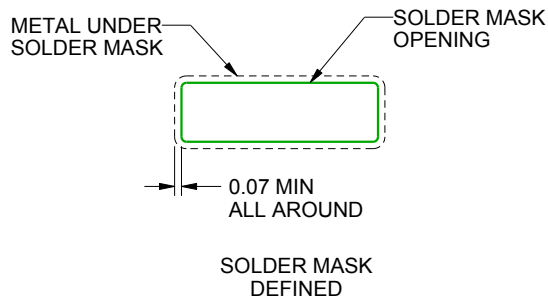
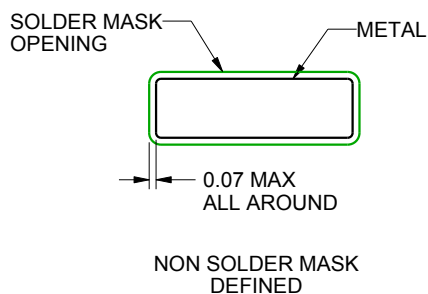
DW0020A

SOIC - 2.65 mm max height

SOIC



LAND PATTERN EXAMPLE
SCALE:6X



SOLDER MASK DETAILS

4220724/A 05/2016

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DW0020A

SOIC - 2.65 mm max height

SOIC



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:6X

4220724/A 05/2016

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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